

1200V/20A

SiC Schottky Barrier Diode

Characteristic

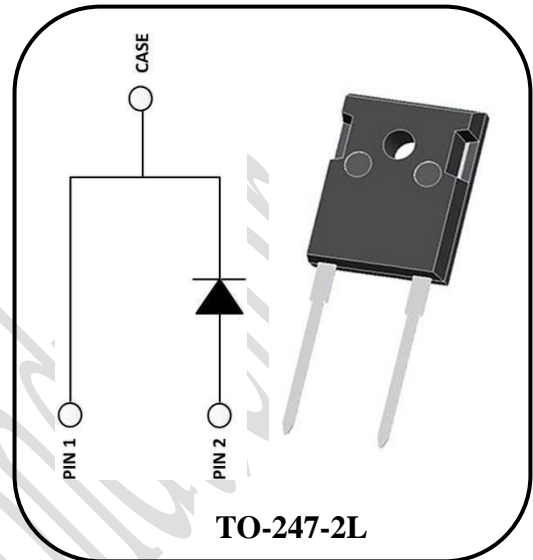
- Zero Reverse Recovery Current
- Positive temperature coefficient
- Temperature-independent performance
- High-speed switching
- Low switching loss
- Low heat dissipation requirements

Application

- Switching power supply
- Power factor correction
- Motor drive, traction
- Charging pile

Product Description

V_{RRM}	1200	V
$I_F(135^\circ\text{C})$	25	A
Q_C	102	nC



Device	Package	Marking
SDS120J020H2	TO-247-2L	DS120020H2

Absolute Maximum Ratings

Parameter	Symbol	Value	Unit	Test Conditions
Reverse voltage (Repetitive peak)	V_{RRM}	1200	V	$T_C=25^\circ\text{C}$
Reverse Voltage (Surge peak)	V_{RSM}	1200		$T_C=25^\circ\text{C}$
Reverse voltage (DC)	V_{DC}	1200		$T_C=25^\circ\text{C}$
Continuous forward current	I_F	55	A	$T_C=25^\circ\text{C}$
		25		$T_C=135^\circ\text{C}$
		20		$T_C=149^\circ\text{C}$
Surge non-repetitive forward current	I_{FSM}	180	A	$T_C=25^\circ\text{C}, t_p=10\text{ms}, \text{half Sine Pulse}$
Repetitive Peak Forward Surge Current	I_{FRM}	112	A	$T_C=25^\circ\text{C}, t_p=10\text{ms}, \text{half Sine Wave } D=0.1$
Total power dissipation	P_{TOT}	220	W	$T_C=25^\circ\text{C}$
i^2t value	$\int i^2 dt$	200	A^2s	$T_C=25^\circ\text{C}, t_p=10\text{ms}$
Operating temperature	T_j	-55~175	$^\circ\text{C}$	
storage temperature	T_{stg}	-55~175	$^\circ\text{C}$	
Mounting Torque	M	1	Nm	M3 Screw

Thermal Characteristics

Parameter	Symbol	Values			Unit	Test Condition
		Min.	Typ.	Max.		
Thermal resistance	$R_{th(j-c)}$	/	0.68	/	$^{\circ}\text{C}/\text{W}$	

Electrical Characteristics $T_j=25^{\circ}\text{C}$

Parameter	Symbol	Values			Unit	Test Condition
		Min.	Typ.	Max.		
DC blocking voltage	V_{DC}	1200	/	/	V	$I_R=100\ \mu\text{A}$
Forward voltage	V_F	/	1.45	1.80	V	$I_F=20\text{A}, T_j=25^{\circ}\text{C}$
		/	2.20	2.70		$I_F=20\text{A}, T_j=175^{\circ}\text{C}$
Reverse current	I_R	/	2	50	μA	$V_R=1200\text{V}, T_j=25^{\circ}\text{C}$
		/	15	300		$V_R=1200\text{V}, T_j=175^{\circ}\text{C}$
Total capacitance	C	/	1453	/	pF	$V_R=0\text{V}, f=1\text{MHz}$
		/	95	/		$V_R=400\text{V}, f=1\text{MHz}$
		/	72	/		$V_R=800\text{V}, f=1\text{MHz}$
Total capacitive charge	Q_C	/	102	/	nC	$V_R=800\text{V}$
Capacitance Stored Energy	E_C	/	29	/	μJ	$V_R=800\text{V}$

Typical Electrical Characteristics Curves

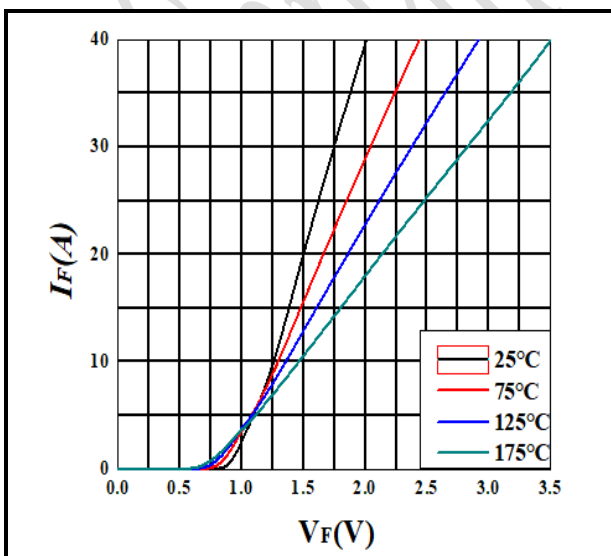


Figure 1. Forward Characteristics

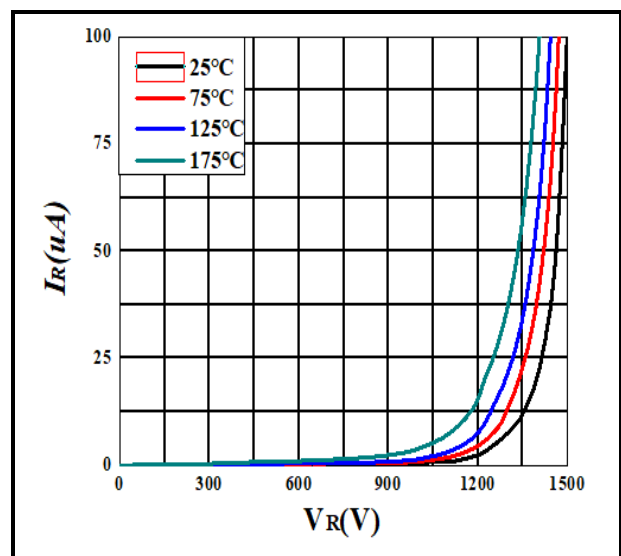


Figure 2. Reverse Characteristics

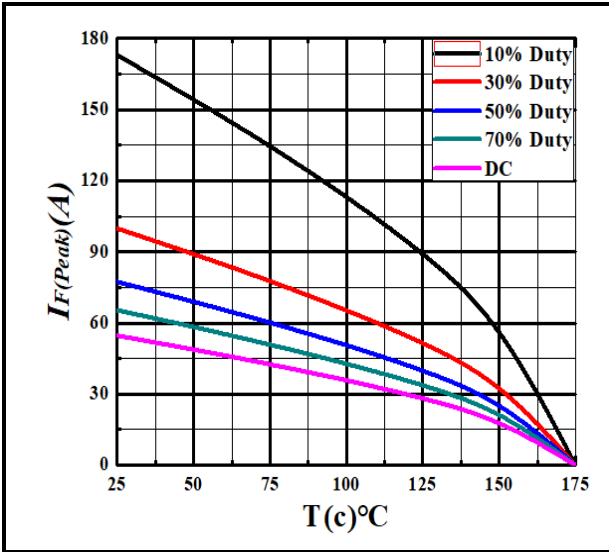


Figure 3. Current Derating

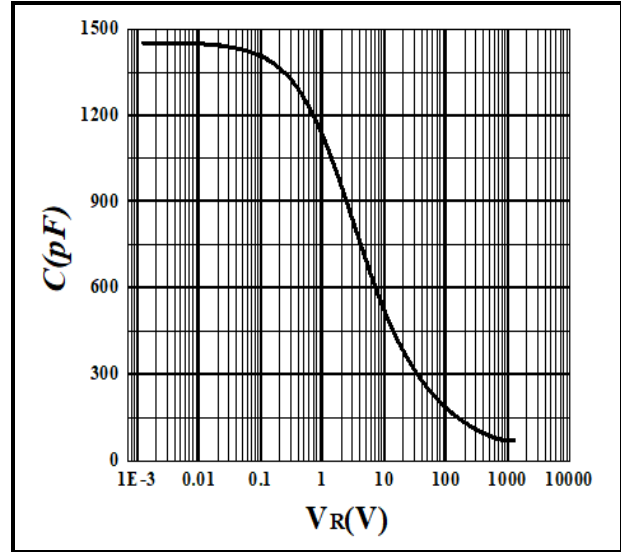


Figure 4. Capacitance vs. Reverse Voltage

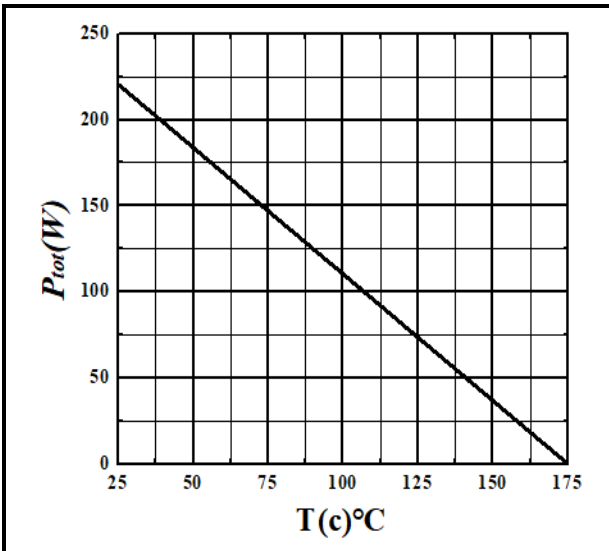


Figure 5. Power Derating

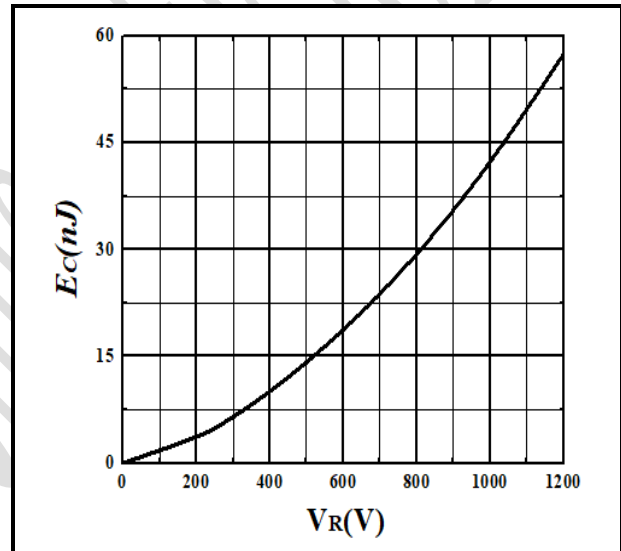


Figure 6. Capacitance Stored Energy

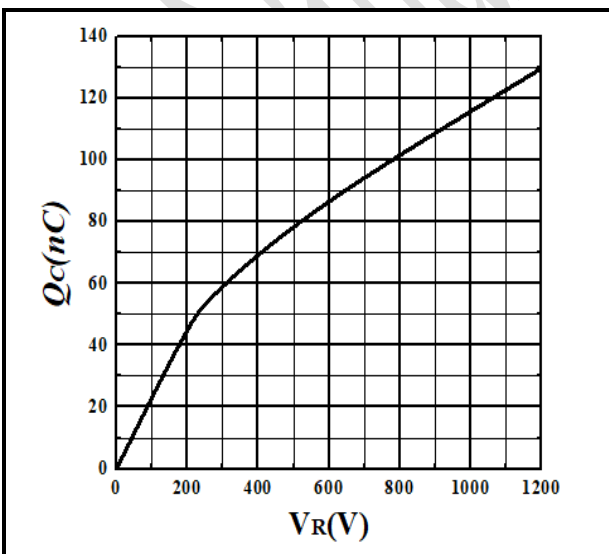
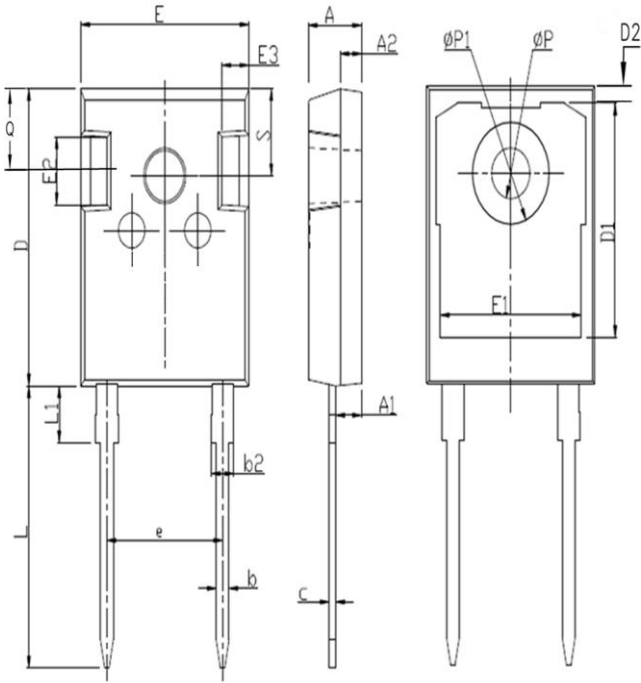


Figure 7. Total Capacitance Charge vs. Reverse Voltage

Package



SYMBOL	mm		
	MIN	NOM	MAX
A	4.8	5	5.2
A1	2.21	2.41	2.61
A2	1.85	2	2.15
b	1.11	1.21	1.36
b2	1.91	2.01	2.21
b4	2.91	3.01	3.21
c	0.51		
D	20.7	21	21.3
D1	16.25	16.55	16.85
D2	1	1.2	1.35
E	15.5	15.8	16.1
E1	13	13.3	13.6
E2	4.8	5	5.2
E3	2.3	2.5	2.7
e	10.88 BSC		
L	19.62	19.92	20.22
L1	-	-	4.3
φP	3.4	3.6	3.8
φP1	-	-	7.3
Q	5.4	5.8	6.2
S	6.20 BSC		

Ordering information

Part Number	SDS120J020H2-ISATH
Package	TO-247-2L
Unit Quantity	300 EA
Packing Type	Tube
RoHS	Yes